

February 2009

FFD04H60S

Features

- Hyperfast Recovery, t_{rr} = 60 ns (@ I_F = 4 A)
- Max Forward Voltage, V_F = 2.1 V (@ T_C = 25°C)
- 600V Reverse Voltage and High Reliability
- · Avalanche Energy Rated
- · RoHS Compliant

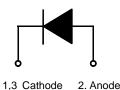
Applications

- General Purpose
- Switching Mode Power Supply
- Free-Wheeling Diode for Motor Application
- Power Switching Circuits

4 A, 600 V, Hyperfast II Diode

The FFD04H60S is a hyperfast II diode and silicon nitride passivated ion-implanted epitaxial planar construction. This device is intended for use as freewheeling/clamping diodes in a variety of switching power supplies and other power switching applications. Its low stored charge and hyperfast soft recovery minimize ringing and electrical noise in many power switching circuits reducing power loss in the switching transistors.





Absolute Maximum Ratings T_C = 25°C unless otherwise noted

Symbol	Parameter	Rating	Unit	
V_{RRM}	Peak Repetitive Reverse Voltage	600	V	
V _{RWM}	Working Peak Reverse Voltage	600	V	
V_R	DC Blocking Voltage	600	V	
I _{F(AV)}	Average Rectified Forward Current @ T _C = 130°C	4	Α	
I _{FSM}	Non-repetitive Peak Surge Current 60Hz Single Half-Sine Wave	40	А	
T _J , T _{STG}	Operating and Storage Temperature Range	-65 to +150	οС	

Thermal Characteristics

Symbol	Parameter	Rating	Unit
R_{\thetaJC}	Maximum Thermal Resistance, Junction to Case	4.0	°C/W

Package Marking and Ordering Information

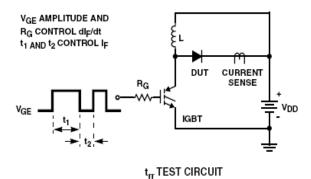
Device Marking	Device	Package	Reel Size	Tape Width	Quantity
F04H60S	FFD04H60S	D-PAK	13"Dia	-	2500

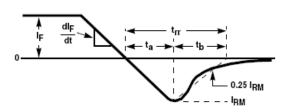
Electrical Characteristics $T_C = 25^{\circ}C$ unless otherwise noted

Symbol	Parameter	Min.	Тур.	Max.	Unit	
V _F 1	I _F = 4 A	$T_{\rm C} = 25^{\rm o}{\rm C}$ $T_{\rm C} = 125^{\rm o}{\rm C}$	-	-	2.1	V
	I _F = 4 A	$T_{\rm C} = 125^{\rm o}{\rm C}$	-	-	1.7	V
I _R 1	V _R = 600 V	$T_{\rm C} = 25^{\rm o}{\rm C}$ $T_{\rm C} = 125^{\rm o}{\rm C}$	-	-	100	
	V _R = 600 V	$T_{\rm C} = 125^{\rm o}{\rm C}$	-	-	200	μА
T _{rr}	$I_F = 1 \text{ A}, \text{ di/dt} = 100 \text{ A/}\mu\text{s}, \text{ V}_{CC} = 30 \text{ V}$	$T_{\rm C} = 25^{\rm o}{\rm C}$ $T_{\rm C} = 25^{\rm o}{\rm C}$	-	19	-	
	$I_F = 4 \text{ A}$, di/dt = 100 A/ μ s, $V_{CC} = 390 \text{ V}$	$T_{\rm C} = 25^{\rm o}{\rm C}$	-	25	60	ns
I _{rr} Q _{rr}	$I_F = 4 \text{ A}, \text{ di/dt} = 100 \text{ A/}\mu\text{s}, \text{ V}_{CC} = 390 \text{ V}$	T _C = 25°C	-	1.5	-	Α
		1 _C = 25°C	-	18	-	nC
W _{AVL}	Avalanche Energy (L = 40 mH)	4	-	-	mJ	

Notes: 1: Pulse: Test Pulse width = 300 μs, Duty Cycle = 2%

Test Circuit and Waveforms

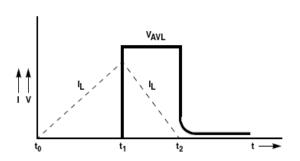




t_{rr} WAVEFORMS AND DEFINITIONS

L = 40mH $R < 0.1\Omega$ E_{AVL} = 1/2LI² $Q_1 = IGBT (BV_{CES} > DUT V_{R(AVL)})$ CURRENT v_{DD} SENSE v_{DD} DUT - r

AVALANCHE ENERGY TEST CIRCUIT



AVALANCHE CURRENT AND VOLTAGE WAVEFORMS

Typical Performance Characteristics

Figure 1. Typical Forward Voltage Drop vs. Forward Current

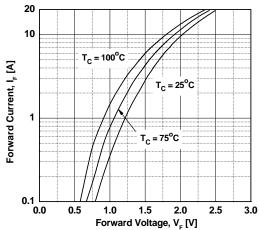


Figure 3. Typical Junction Capacitance

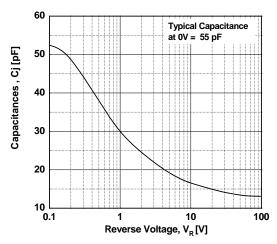


Figure 5. Typical Reverse Recovery Current vs. di/dt

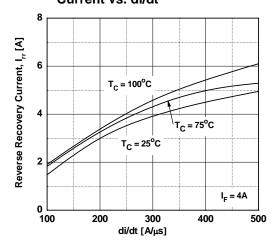


Figure 2. Typical Reverse Current vs.

Reverse Voltage

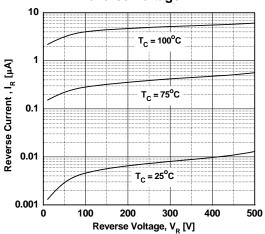


Figure 4. Typical Reverse Recovery Time vs. di/dt

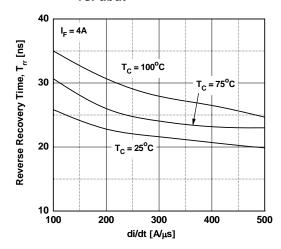
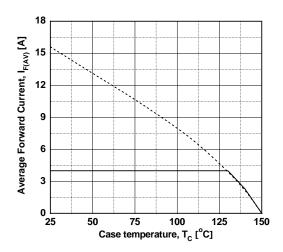
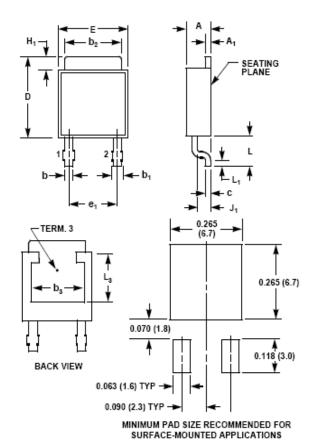


Figure 6. Forward Current Derating Curve



Mechanical Dimensions

D-PAK



	INCHES		MILLIMETERS		
SYMBOL	MIN	MAX	MIN	MAX	NOTES
Α	0.086	0.094	2.19	2.38	-
A ₁	0.018	0.022	0.46	0.55	3, 4
b	0.028	0.032	0.72	0.81	3, 4
b ₁	0.033	0.040	0.84	1.01	3
b ₂	0.205	0.215	5.21	5.46	3, 4
b ₃	0.190	-	4.83	-	2
С	0.018	0.022	0.46	0.55	3, 4
D	0.270	0.290	6.86	7.36	-
Е	0.250	0.265	6.35	6.73	-
e ₁	0.180 BSC		4.57 BSC		6
H ₁	0.035	0.045	0.89	1.14	-
J ₁	0.040	0.045	1.02	1.14	-
L	0.100	0.115	2.54	2.92	-
L ₁	0.020	-	0.51	-	3, 5
L ₃	0.170	-	4.32	-	2

NOTES:

- 1. No current JEDEC outline for this package.
- L₃ and b₃ dimensions establish a minimum mounting surface for terminal 3.
- 3. Dimension (without solder).
- 4. Add typically 0.002 inches (0.05mm) for solder plating.
- L₁ is the terminal length for soldering.
 Position of lead to be measured 0.090 inches (2.28mm) from bottom of dimension D.
- 7. Controlling dimension: Inch.
- 8. Revision 8 dated 5-99.





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